NSN 5961-01-072-8151

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-072-8151 **Inclosure Material:** Metal **Overall Length:** 1.250 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-double base Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 800.0 nonrepetitive peak off-state voltage **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn. **Test Data Document:** 24930-g390166 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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